

Trans MOSFET N-CH 75V 30A Automotive 3-Pin(2+Tab) DPAK T/R

Manufacturers	Infineon Technologies Corporation
Package/Case	TO-252
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for IPD30N08S2L-21 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

IPD30N08S2L-21 is a MOSFET (metal-oxide-semiconductor field-effect transistor) that is designed for high-performance power management applications. Here are some of its features:

Features

- VDS (drain-source voltage) rating of 80V
- ID (continuous drain current) rating of 30A
- RDS(on) (on-state resistance) rating of 21mΩ at >
- Low gate charge of 33nC
- TO-252 (DPAK) package

Application

- Power supplies
- Motor control
- DC-DC converters
- LED lighting
- Automotive systems



Related Products



[IPP60R070CFD7](#)

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TO-220-3



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